



DMTH12H007SPS

120V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on) Max	I _D Tc = +25°C (Note 10)
120V	$8.5m\Omega @ V_{GS} = 10V$	100A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Switching

Notes:

DC-DC Converters

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low RDS(ON) Minimizes On-State Losses
- <1.1mm Package Profile Ideal for Thin Applications</p>
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 🕄

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Weight: 0.097 grams (Approximate)

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Internal Schematic



Ordering Information (Note 4)

Part Number	Case	Packaging
DMTH12H007SPS-13	PowerDI5060-8	2,500 / Tape & Reel

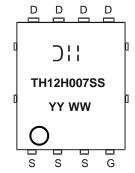
EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

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3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



) | | = Manufacturer's Marking
TH12H007SS = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 20 = 2020)
WW = Week Code (01 to 53)

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Document number: DS42125 Rev. 3 - 2

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Top View

Pin Configuration



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	120	V	
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current, V _{GS} = 10V (Note 6)	Tc = +25°C (Note 10) Tc = +100°C	ID	100 72	А
Pulsed Drain Current (10µs Pulse, Tc = +25°C, Package Limited)		Ідм	400	А
Continuous Body Diode Forward Current (Note 6)	Tc = +25°C	ls	86	А
Pulsed Body Diode Current (10 μ s Pulse, T _C = +25°C, Package Limited) T _C = +25°C		lsм	400	А
Avalanche Current, L = 3mH (Note 9)	I _{AS}	15.5	А	
Avalanche Energy, L = 3mH (Note 9)		Eas	360.4	mJ

Thermal Characteristics

Characteristic	Symbol	Value (Typ.)	Unit
Total Power Dissipation (Note 5)	PD	3.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Reja	43	°C/W
Total Power Dissipation (Note 6)	PD	125	W
Thermal Resistance, Junction to Case (Note 6)	Rejc	1.2	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +175	٥°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

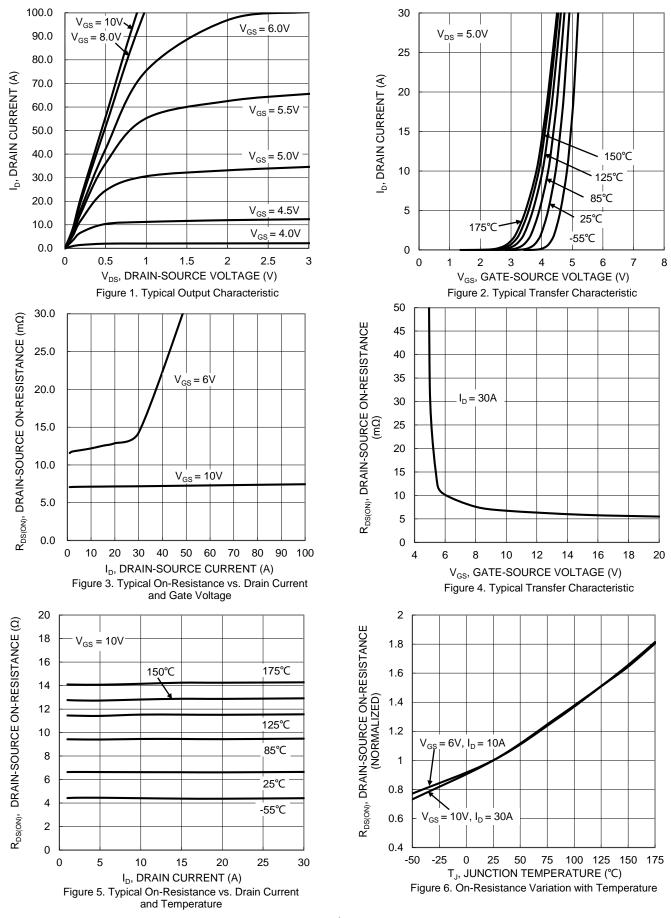
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	Cymber		. , , ,	max	Unit		
Drain-Source Breakdown Voltage	BVDSS	120	_		V	$V_{GS} = 0V, I_D = 10mA$	
Zero Gate Voltage Drain Current	IDSS		_	1	μA	V _{DS} = 96V, V _{GS} = 0V	
Gate-Source Leakage	IGSS		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	2	_	4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		_	6.6	8.5	mΩ	Vgs = 10V, ID = 30A	
Static Drain-Source On-Resistance	Rds(on)	_	12	16	11177	VGS = 6V, ID = 10A	
Diode Forward Voltage	V _{SD}	_	0.8	1.2	V	$V_{GS} = 0V, I_{S} = 30A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	3142	_		$V_{DS} = 60V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss	_	665	_	pF		
Reverse Transfer Capacitance	Crss	_	29	_			
Gate Resistance	R _G		1.9		Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 10V)	Qg	_	44				
Gate-Source Charge	Qgs		15		nC	V _{DS} = 60V, I _D = 25A	
Gate-Drain Charge	Qgd		9				
Turn-On Delay Time	tD(ON)		12.5			$V_{DD} = 60V, V_{GS} = 10V,$ $I_D = 25A, R_G = 2.7\Omega$	
Turn-On Rise Time	tR		13.7				
Turn-Off Delay Time	tD(OFF)		24.4		ns		
Turn-Off Fall Time	tF		10.9	—			
Reverse Recovery Time	trr	_	55	_	ns		
Reverse Recovery Charge	Qrr		105	_	nC	IF = 25A, di/dt = 100A/μs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:

9. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$. 10. Package limited.

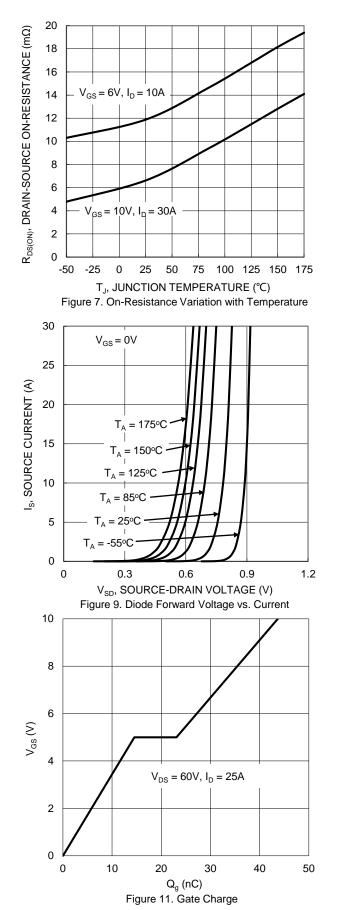


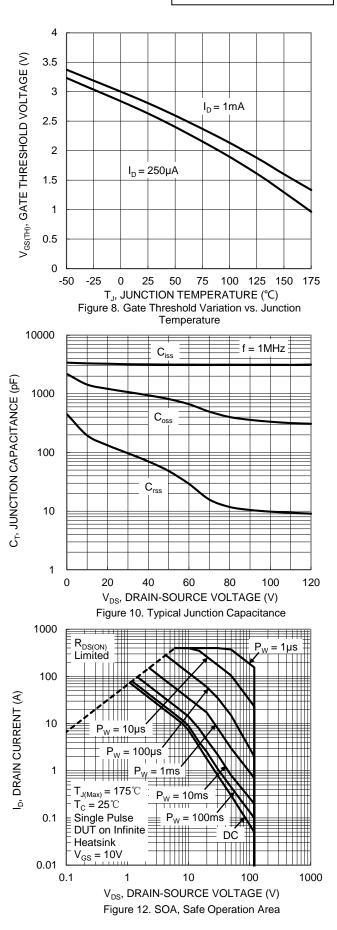
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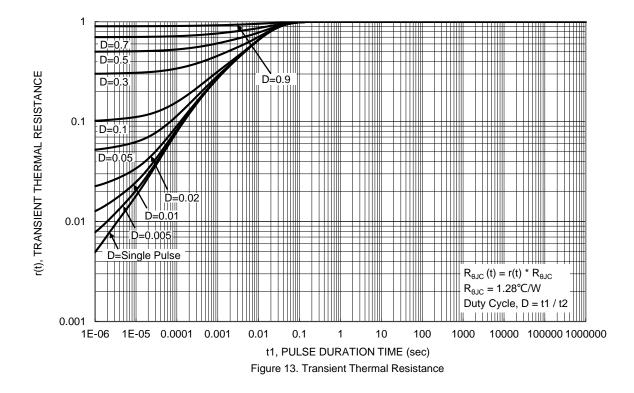






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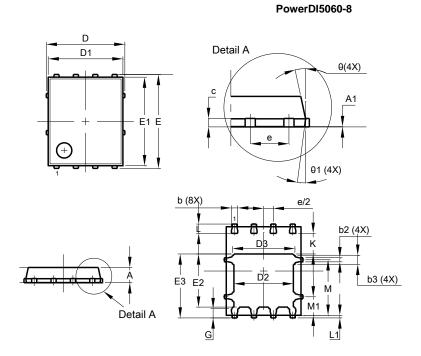






Package Outline Dimensions

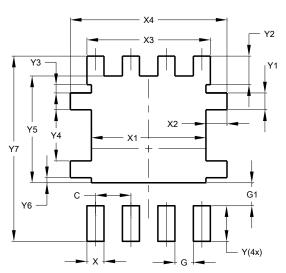
Please see http://www.diodes.com/package-outlines.html for the latest version.



	PowerDI5060-8				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
c	0.230	0.330	0.277		
D		5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90				
ш	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
e	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	—	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
Al	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
¥7	6.610

PowerDI5060-8



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